NSN 5961-00-883-8949

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View Online at https://aerobasegroup.com/nsn/5961-00-883-8949

Inclosure Material:	
Metal	
Overall Length:	
Between 0.240 inches and 0.260 inches	
Terminal Length:	
1.500 inches	
Overall Diameter:	
Between 0.335 inches and 0.370 inches	
Internal Configuration:	
Junction contact	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.200 inches	
Features Provided:	
Gold plated leads and hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
80.0 collector to base voltage, dc and 50.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,	instantaneous
Current Rating Per Characteristic:	
1.20 amperes source cutoff current	
Power Rating Per Characteristic:	
10.0 watts small-signal input power, common-collector	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: npn	
Precious Material And Location:	
Terminal surfaces gold	
Precious Material:	
Gold	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	

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